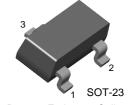


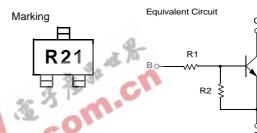
# **FJV3101R**

# Switching Application (Bias Resistor Built In)

- Switching circuit, Inverter, Interface circuit, Driver Circuit
  Built in bias Resistor (R1=4.7ΚΩ, R2=4.7ΚΩ)
- Complement to FJV4101R



1. Base 2. Emitter 3. Collector



# **NPN Epitaxial Silicon Transistor**

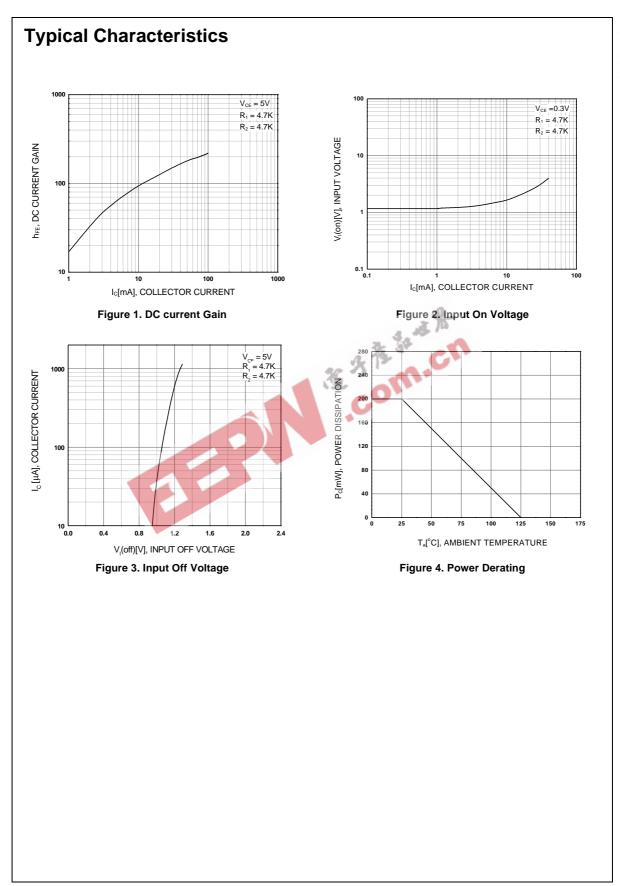
### Absolute Maximum Ratings Ta=25°C unless otherwise noted

Symbol	Parameter	Value	Units
$V_{CBO}$	Collector-Base Voltage	50	V
$V_{CEO}$	Collector-Emitter Voltage	50	V
V <sub>EBO</sub>	Emitter-Base Voltage	10	V
I <sub>C</sub>	Collector Current	100	mA
P <sub>C</sub>	Collector Power Dissipation	200	mW
T <sub>J</sub>	Junction Temperature	150	°C
T <sub>STG</sub>	Storage Temperature	-55 ~ 150	°C

# Electrical Characteristics $T_a=25$ °C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV <sub>CBO</sub>	Collector-Base Breakdown Voltage	$I_{C}=10\mu A, I_{E}=0$	50			V
BV <sub>CEO</sub>	Collector-Emitter Breakdown Voltage	$I_C=100\mu A, I_B=0$	50			V
I <sub>CBO</sub>	Collector Cut-off Current	$V_{CB}$ =40V, $I_E$ =0			0.1	μΑ
h <sub>FE</sub>	DC Current Gain	V <sub>CE</sub> =5V, I <sub>C</sub> =10mA	20			
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage	I <sub>C</sub> =10mA, I <sub>B</sub> =0.5mA			0.3	V
f <sub>T</sub>	Current Gain Bandwidth Product	V <sub>CE</sub> =10V, I <sub>C</sub> =5mA		250		MHz
C <sub>ob</sub>	Output Capacitance	V <sub>CB</sub> =10V, I <sub>E</sub> =0 f=1.0MHz		3.7		pF
V <sub>I</sub> (off)	Input Off Voltage	$V_{CE}=5V, I_{C}=100\mu A$	0.5			V
V <sub>I</sub> (on)	Input On Voltage	V <sub>CE</sub> =0.3V, I <sub>C</sub> =20mA			3	V
R <sub>1</sub>	Input Resistor		3.2	4.7	6.2	ΚΩ
R <sub>1</sub> /R <sub>2</sub>	Resistor Ratio		0.9	1	1.1	

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# **Package Demensions** SOT-23 0.20 MIN 0.45~0.60 $0.40 \pm 0.03$ 1.30 ±0.10 0.03~0.10 0.38 REF $0.12^{\,+0.05}_{\,-0.023}$ 0.40 ±0.03 0.96~1.14 2.90 ±0.10 0.97REF 0.95 ±0.03 0.95 ±0.03 1.90 ±0.03 0.508REF Dimensions in Millimeters

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$CROSSVOLT^{TM}$	GTO™	$POP^{\mathsf{TM}}$	SuperSOT™-3	
DOME™	HiSeC™	Power247™	SuperSOT™-6	
EcoSPARK™	I <sup>2</sup> C™	PowerTrench <sup>®</sup>	SuperSOT™-8	
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EnSigna™	LittleFET™	QS™	TinyLogic™	
FACT™	MicroFET™	QT Optoelectronics™	TruTranslation™	
FACT Quiet series™	MicroPak™	Quiet Series™	UHC™	
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